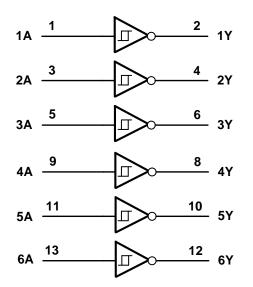


Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	ЗA	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs	Outputs	
Α	Y	
Н	L	
L	Н	



Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or IOFF state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V ₁ < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
Ι _Ο	Continuous output current	50	mA
	Continuous current through V _{DD} or GND	±100	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT} Total Power Dissipation		500	mW

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		1.65	5.5	V
VI	Input Voltage		0	5.5	V
M		Active Mode	0	V _{CC}	V
Vo	Output Voltage	V _{CC} = 0V; Power Down Mode	0	5.5	V
TA	Operating free-air temperature		-40	+125	٥C

Note: 5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

.		Tako katiki		T _A = -40°C	to +85°C	T _A = -40°C	to +125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
			2.5V	0.9	1.7	0.9	1.7	
V_{T+}	Positive Going	-	2.7V	1.1	2.0	1.1	2.0	V
	Threshold		2.7V to 3.6V	1.1	2.0	1.1	2.0	
			2.5V	0.4	1.2	0.4	1.2	
V _T .	Negative Going Threshold		2.7V	0.8	1.5	0.8	1.5	V
	Threshold		2.7V to 3.6V	0.8	1.5	0.8	1.5	
			2.5V	0.3		0.2		
Vн	Hysteresis (V _{T+ -} V _{T-)}		2.7V	0.3		0.3		
	(VT+-VT-)		2.7V to 3.6V	0.3		0.3		
		Ι _{ΟΗ} = -100μΑ	1.65V to 3.6V	$V_{CC} - 0.2$		V _{CC} -0.3		
		I _{OH} = -4mA	1.65V	1.2				
.,	High Level	I _{OH} = -8mA	2.3V	1.9				.,
V _{OH}	Output Voltage		2.7V	2.2		2.05		V
		I _{OH} = -12mA	3.0V	2.3		2.1		
		I _{OH} = -24mA	3.0V	2.2		2.0		
		I _{OH} = 100μA	1.65V to 5.5V		0.2		0.3	
		I _{OH} = 4mA	1.65V		0.45		0.6	
V	High-level	I _{OH} = 8mA	2.3V		0.70		0.85	Ň
V _{OL}	Output Voltage	40	2.7V		0.40		0.6	V
		I _{OH} = 12mA	3.0V		0.55		0.6	
		I _{OH} =-24 mA	3.0V		0.55		0.6	
l _l	Input Current	V _I =GND to 5.5V	3.6V		± 5		± 20	μA
IOFF	Power Down Leakage Current	$V_1 \text{ or } V_0 = 0V \text{ to } 3.6V$	0		10		20	μA
I _{CC}	Supply Current	$V_I = GND \text{ or}$ $V_{CC} I_O=0$	3.6V		10		40	μA
ΔI _{CC}	Additional Supply Current	One input at V _{CC} –0.6 V Other	2.7V to 3.6V		500		5000	μA



Switching Characteristics

Symbol	Parameter	Test	V	T,	₄ = +25°	°C	-40°C to	o +85°C	-40°C to	+125°C	Unit
Symbol	Parameter	Conditions	V _{cc}	Min	Тур	Max	Min	Max	Min	Max	Unit
			1.65V to1.95V	0.5	4.1	8.9	0.5	8.9	0.5	9.5	
	Propagation	Figure 1	2.3V to 2.7V	0.5	3.6	7.0	0.5	7.5	0.5	9.0	
t _{PD}	Delay A_{N} to Y_{N}	Figure 1	2.7V	0.5	3.0	5.3	0.5	5.5	0.5	7.0	ns
			3V to 3.6V	0.5	2.5	4.8	0.5	4.8	0.5	6.0	
t _{SK(0)}	Output Skew Time		3V to 3.6V					1.0		1.5	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 1.8V Typ	V _{cc} = 2.5V Typ	V _{CC} = 3.3V Typ	V _{cc} = 5V Typ	Unit
C _{pd}	Power dissipation capacitance per gate	f = 10MHz	7.0	7.5	8.0	8.6	pF
CI	Input Capacitance	V _i = V _{CC} – or GND	4	4	4	4	pF

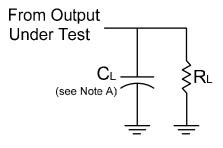
Package Characteristics

Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур	Max	Unit
0	Thermal Resistance	SO-14			TBD		°C/W
θ _{JA}	Junction-to-Ambient	TSSOP-14	(Note 6)		159		
0	Thermal Resistance	SO-14	(Nata C)		TBD		°C/W
θ _{JC}	Junction-to-Case	TSSOP-14	(Note 6)		25		C/W

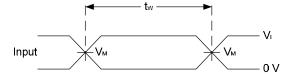
Note: 6. Test condition for SO-14 and TSSOP-14: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



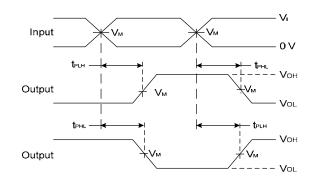
Parameter Measuement Information



V	Inputs		V	C	в	
V _{cc}	VI	t _r /t _f	V _M	CL	RL	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω	
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

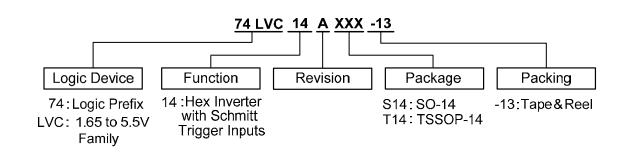
Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1. Load Circuit and Voltage Waveforms



Ordering Information

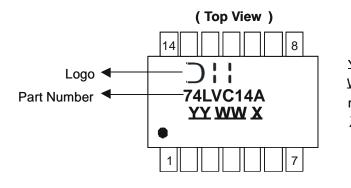


	Device	Package Packaging		13" Tape and Reel		
	Device	Code	(Note 7)	Quantity	Part Number Suffix	
Pb ,	74LVC14AS14-13	S14	SO-14	2500/Tape & Reel	-13	
PD,	74LVC14AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13	

Notes: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-14, TSSOP-14



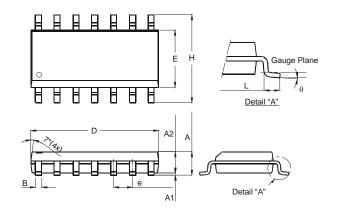
YY : Year : 08, 09,10~ WW : Week : 01~52; 52 represents 52 and 53 week Δ : Internal Code

Part Number	Package
74LVC14AS14	SO-14
74LVC14AT14	TSSOP-14



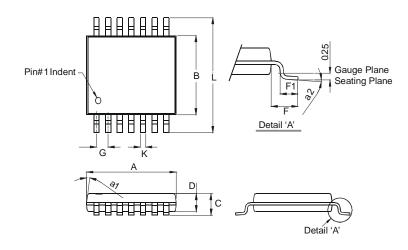
Package Outline Dimensions (All dimensions in mm.)

Package Type: SO-14



	SO-14	
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27	Тур
н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Di	mensions	s in mm

Package Type: TSSOP-14



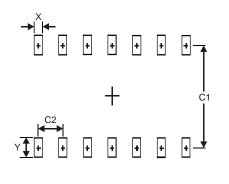
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С		1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Тур	
κ	0.19	0.30
L	6.40 Тур	
All Dimensions in mm		



74LVC14A

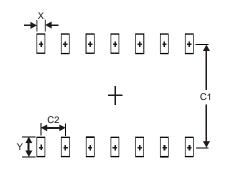
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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